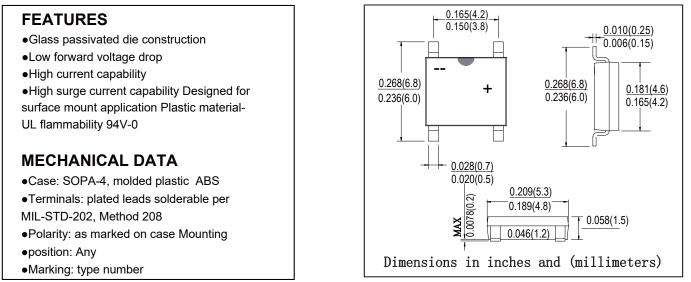


ABS SILICON BRIDGE RECTIFIERV

REVERSEVOLTAGE:200 --- 1000V CURRENT: 2.0A



Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single Phase, half wave, 60Hz, resistive or inductive load.

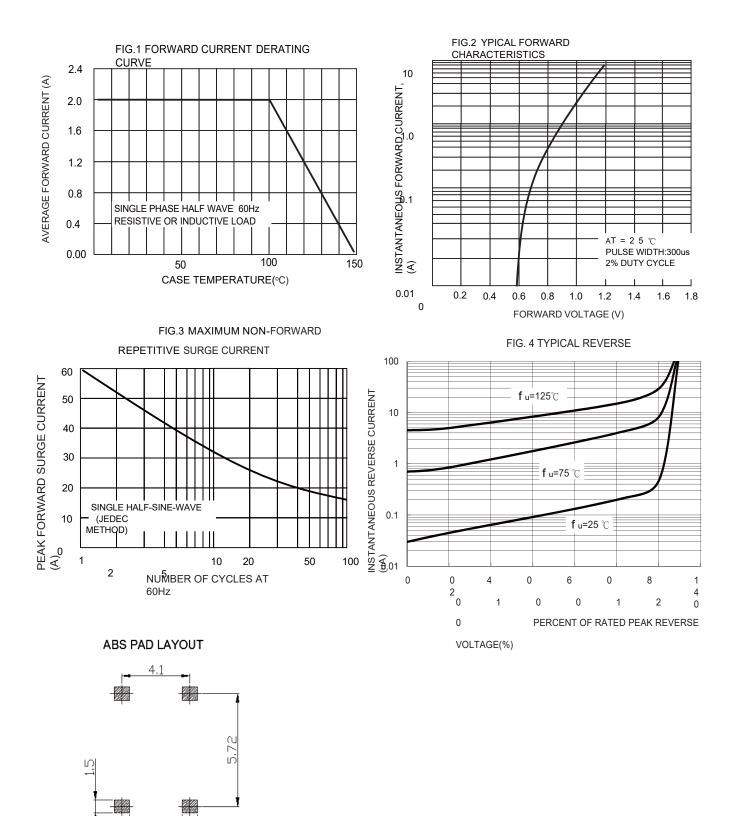
For capacitive load, derate current by 20%.

TYPE NUMBER	SYMBOL	ABS22	ABS24	ABS26	ABS28	ABS210	UNITS
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm	200	400	600	800	1000	v
	Vrwm						
	Vdc						
RMS Reverse Voltage	VRMS	140	280	420	560	700	V
Average Rectified Output Current $@f\circ$ =100 $^\circ C$	IF(AV)	2.0					А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	Ifsm	60					A
Rating for fusing (t<8.3ms)	l²t	14.94					A²s
Forward Voltage per element @IF=1.0A @IF=2.0A	Vfm	0.95 1.0					V
Peak Reverse Current@f A =25℃At Rated DC Blocking Voltage@f A =125℃	lr	5.0 200					uA
Typical Thermal Resistance per leg	R_ja	62.5					°C/W
	R_j∟	25					
Operating and Storage Temperature Range	Тј,Tstg	-55to+150					°C





RATINGS AND CHARACTERISTIC CURVES



0,9